

3Q Hi-Com Triac Rev. 2 — 20 December 2011

Product data sheet

1. Product profile

1.1 General description

Planar passivated high commutation three quadrant triac in a SOT186A (TO-220F) "full pack" plastic package. This "series ET" triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers including microcontrollers. It is used where "high junction operating temperature" capability ($T_i = 150$ °C) is required.

1.2 Features and benefits

- 3Q technology for improved noise immunity
- Direct interfacing with low power drivers and microcontrollers
- Good immunity to false turn-on by dV/dt
- High commutation capability with sensitive gate

1.3 Applications

Quick reference data

- Applications subject to high temperature
- Electronic thermostats (heating and cooling)

capability

High voltage capability

High junction operating temperature

- Isolated mounting base package
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only
- Motor controls for home appliances
- Refrigeration and air-conditioner compressor controls

1.4 Quick reference data

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	-	60	A
Tj	junction temperature		-	-	150	°C
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 114 °C; see <u>Figure 1;</u> see <u>Figure 2;</u> see <u>Figure 3</u>	-	-	6	A



Table 1.

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; see <u>Figure 7</u>	-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; see <u>Figure 7</u>	-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; see <u>Figure 7</u>	-	-	10	mA
Dynamic of	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	50	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 6 \text{ A};$ $dV_{com}/dt = 1 \text{ V}/\mu s;$ gate open circuit	5	-	-	A/ms

Table 1. Quick reference data ...continued

2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		N.
2	T2	main terminal 2	mb	
3	G	gate		`G sym051
mb	n.c.	mounting base; isolated		

1 2 3 SOT186A (TO-220F)

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3. Ordering information

Table 3. Ordering	g information		
Type number Package			
	Name	Description	Version
BTA206X-800ET	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A

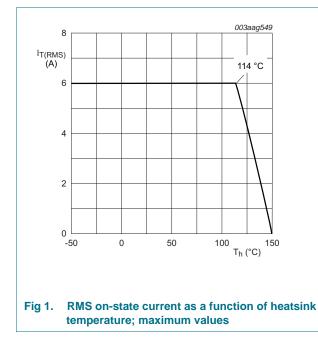
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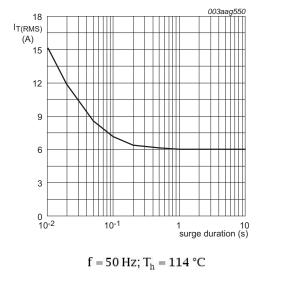
4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 114 °C; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	6	А
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	60	А
		full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 16.7 \text{ ms}$	-	66	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	18	A ² s
dl _T /dt	rate of rise of on-state current	I_T = 10 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



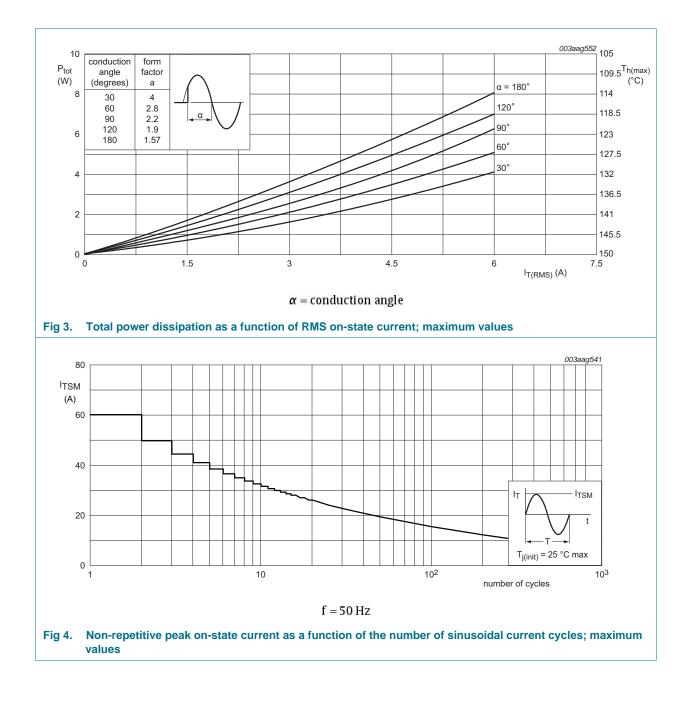




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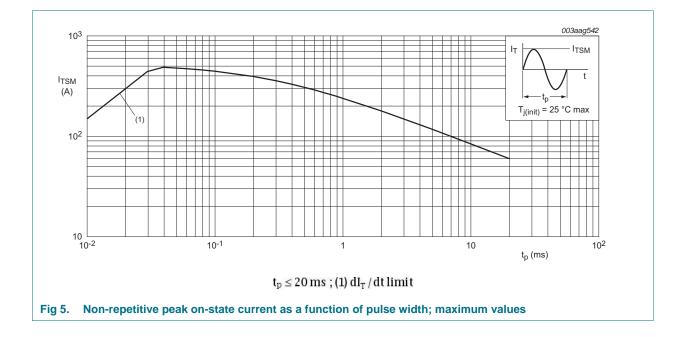
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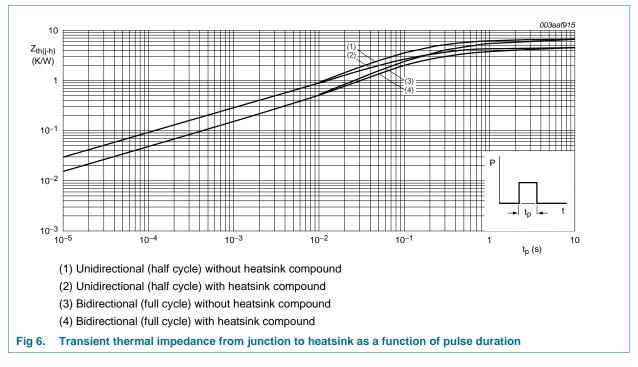
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5. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	full cycle or half cycle; with heatsink compound; see Figure 6	-	-	4.5	K/W
		full cycle or half cycle; without heatsink compound; see Figure 6	-	-	6.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	55	-	K/W



6. Isolation characteristics

Table 6.	Isolation characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free ; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink ; f = 1 MHz; T_h = 25 °C	-	10	-	pF

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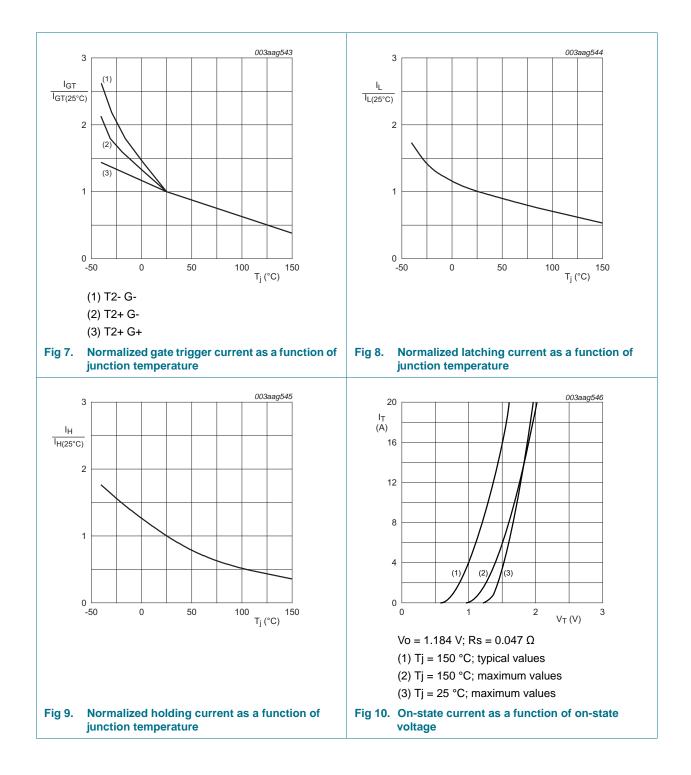
7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{T2+ G+}; \text{T}_j = 25 ^\circ\text{C}; \\ \text{see } \underline{\text{Figure 7}}$	-	-	10	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G-}; \text{T}_j = 25 \text{ °C};$ see <u>Figure 7</u>	-	-	10	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2- G-}; T_j = 25 \text{ °C};$ see Figure 7	-	-	10	mA
IL	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2+ G+}; \text{ T}_j = 25 \text{ °C};$ see <u>Figure 8</u>	-	-	25	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-}; \text{ T}_j = 25 \text{ °C};$ see Figure 8	-	-	30	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-}; \text{ T}_j = 25 \text{ °C};$ see Figure 8	-	-	25	mA
I _H	holding current	$V_D = 12 \text{ V}; \text{ T}_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 9}}{100000000000000000000000000000000000$	-	-	15	mA
V _T	on-state voltage	I _T = 7 A; see <u>Figure 10</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	$V_D = 12 V; I_T = 0.1 A; T_j = 25 °C;$ see <u>Figure 11</u>	-	0.8	1.5	V
		$V_D = 400 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 150 ^\circ\text{C}$	0.25	-	-	V
I _D	off-state current	V _D = 800 V; T _j = 150 °C	-	0.4	2	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_{j} = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	50	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{T}_\text{j} = 150 \text{ °C}; \text{I}_{\text{T}(\text{RMS})} = 6 \text{ A}; $ $dV_{\text{com}}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	1	-	-	A/m
		V_D = 400 V; T_j = 150 °C; $I_{T(RMS)}$ = 6 A; dV _{com} /dt = 10 V/µs; gate open circuit	2	-	-	A/m
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 6 \text{ A};$ $dV_{com}/dt = 1 \text{ V}/\mu\text{s};$ gate open circuit	5	-	-	A/m

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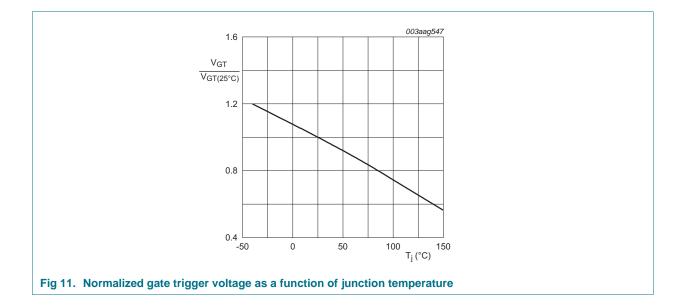
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Package outline 8.

SOT186A F Ρ A₄ q D₁ mounting т base 4 D i ŧ L₂ L_1 ĸ Ā Q b₁ b₂ 2 3 1 **-**⊕ w M b≁ll **-** c е e₁ 0 5 10 mm Luunninnin scale DIMENSIONS (mm are the original dimensions) L₂⁽¹⁾ т⁽²⁾ D D₁ Р Q UNIT Е κ Α с j L L₁ A₁ b b₁ b2 е e₁ q w max 3.30 2.9 1.1 1.4 15.8 2.7 0.6 14.4 2.6 4.6 0.7 6.5 10.3 3.0 0.9 3.2 mm 3 2.54 5.08 2.5 0.4 4.0 2.5 1.0 6.3 1.7 0.4 2.79 3.0 0.9 9.7 13.5 2.3 0.7 0.4 15.2 26 Notes 1. Terminal dimensions within this zone are uncontrolled. 2. Both recesses are \varnothing 2.5 \times 0.8 max. depth REFERENCES OUTLINE EUROPEAN ISSUE DATE PROJECTION VERSION JEDEC JEITA IEC 02-04-09 \blacksquare SOT186A 3-lead TO-220F 06-02-14

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack'

Fig 12. Package outline SOT186A (TO-220F)

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9. Revision history

Table 8. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA206X-800ET v.2	20111220	Product data sheet	-	BTA206X-800ET v.1
Modifications:	 Various changes 	to content.		
BTA206X-800ET v.1	20110822	Product data sheet	-	-

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10. Legal information

10.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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